

TVS Diodes

Transient Voltage Suppression Diodes

SMA6J Series



Description

Transient Voltage Suppressor (TVS) is a circuit protection component that either attenuates (reduces) or filters a transient voltage spike (overvoltage), TVS diodes provide critical protection by going into avalanche breakdown within no more than a few nanoseconds after a strike, clamping the transient voltage, and routing its current to the ground.

Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

Functional Diagram



Uni-Directional

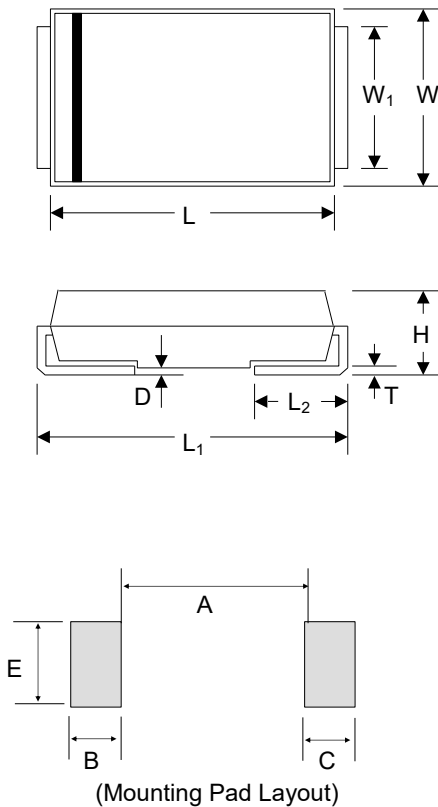


Bi-Directional

Features

- Low incremental surge resistance
- Excellent clamping capability
- Low profile package with built-in strain relief
- Typical I_R less than 1.0 μA above 10 V
- 600 W peak pulse power capability with a 10/1000 μs Waveform
- For surface mounted applications to optimize board space
- Typical failure mode is short from over-specified voltage or current
- IEC 61000-4-2 ESD 30 kV (Air), 30 kV (Contact)
- EFT protection of data lines in accordance with IEC 61000 -4-4
- Very fast response time
- Glass passivated chip junction
- High temperature to reflow soldering guaranteed: 260 °C/30 sec
- Plastic package is flammability rated V-0 per Underwriters Laboratories
- Meet MSL level1, per J-STD-020
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

Package Outline Dimensions (DO-214AC)



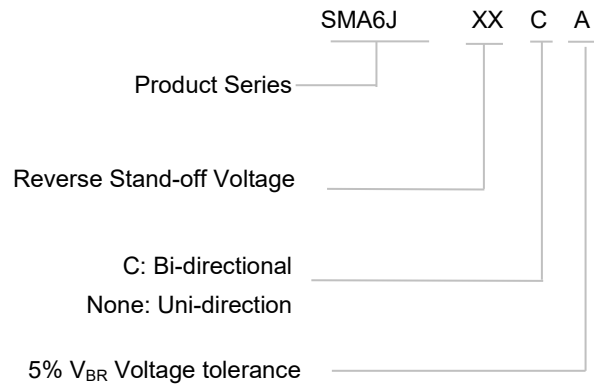
Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
L	3.990	4.600	0.157	0.181
W	2.300	2.790	0.095	0.110
W ₁	1.250	1.650	0.049	0.065
H	1.900	2.290	0.075	0.090
T	0.152	0.305	0.006	0.012
L ₁	4.800	5.280	0.189	0.208
L ₂	0.780	1.520	0.030	0.060
D	-	0.203	-	0.008
A	-	2.300	-	0.090
B	2.100	-	0.082	-
C	2.100	-	0.082	-
E	1.800	-	0.070	-

Maximum Ratings and Characteristics

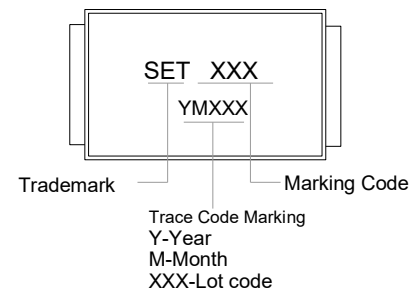
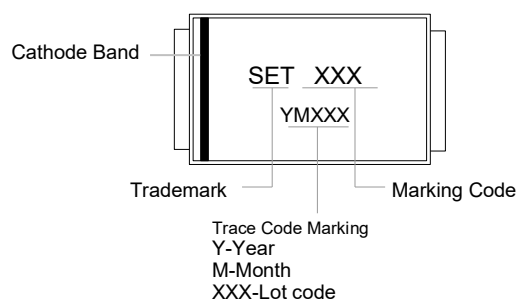
(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Peak Power Dissipation (Fig.2) with a 10/1000 μ S waveform ⁽¹⁾⁽²⁾ (Fig.4)-Single Die Parts	P _{PPM}	600	W
Peak Power Dissipation on Infinite Heat Sink at T _L =50 °C	P _D	5.0	W
Peak Forward Surge Current, 8.3 ms single half sinewave superimposed on rated load (JEDEC Method) ⁽³⁾	I _{FSM}	60	A
Maximum Instantaneous Forward Voltage at 50 A for Unidirectional Only ⁽⁴⁾	V _F	3.5	V
Operating Temperature Range	T _J	-55 to 150	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C
Typical Thermal Resistance Junction to Lead	R _{θJL}	30	°C / W
Typical Thermal Resistance Junction to Ambient	R _{θJA}	120	°C / W

Part Numbering System



Marking



Glossary

Item	Description
V_C	Clamping Voltage Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V_R	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE : It is also shown as V _{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage (V _{so}).
I_R	Reverse Leakage Current Current measured at V _R . NOTE : Also shown as I _D for stand-by current.
V_{BR}	Breakdown Voltage Voltage across TVS at a specified current I _T in the breakdown region.
I_{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P_{M(AV)}	Rated Average Power Dissipation Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P_{PPM}	Rated Random Recurring Peak Impulse Power Dissipation Maximum-rated value of the product of rated random recurring peak impulse current (I _{PPM}) multiplies by specified maximum clamping voltage (V _C).
C_J	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
V_{FS}	Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current (I _{FS}) and time duration. NOTE : Also shown as V _F .
I_{FS}	Forward Surge Current Pulsed current through TVS in the forward conducting region. NOTE : Also shown as I _F .
α_{V(BR)}	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.
I_{PP}	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage V _C for a specified wave shape.
I_T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage V _{BR} . This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE : Also shown as I _{BR} .

—(GB-T 18802.321 / IEC 61643-321 / JESD210A)

Electrical Characteristics (T_A=25 °C unless otherwise noted)Table 1

Part Number		Device Marking Code		Breakdown Voltage V _{BR} @I _T		Test Current I _T	Reverse Stand-off Voltage V _R	Max. Reverse Leakage I _R @V _R	Max. Peak Pulse Current I _{PPM}	Max. Clamping Voltage V _C @I _{PPM}
				Min	Max					
Uni	Bi	Uni	Bi	(V)		(mA)	(V)	(μA)	(A)	(V)
SMA6J5.0A	SMA6J5.0CA	KE	AE	6.4	7	10	5	800	65.3	9.2
SMA6J6.0A	SMA6J6.0CA	KG	AG	6.67	7.37	10	6	800	58.3	10.3
SMA6J6.5A	SMA6J6.5CA	KK	AK	7.22	7.98	10	6.5	500	53.6	11.2
SMA6J7.0A	SMA6J7.0CA	KM	AM	7.78	8.6	10	7	200	50	12
SMA6J7.5A	SMA6J7.5CA	KP	AP	8.33	9.21	1	7.5	100	46.6	12.9
SMA6J8.0A	SMA6J8.0CA	KR	AR	8.89	9.83	1	8	50	44.2	13.6
SMA6J8.5A	SMA6J8.5CA	KT	AT	9.44	10.4	1	8.5	20	41.7	14.4
SMA6J9.0A	SMA6J9.0CA	KV	AV	10	11.1	1	9	10	39	15.4
SMA6J10A	SMA6J10CA	KX	AX	11.1	12.3	1	10	5	35.3	17
SMA6J11A	SMA6J11CA	KZ	AZ	12.2	13.5	1	11	1	33	18.2
SMA6J12A	SMA6J12CA	LE	BE	13.3	14.7	1	12	1	30.2	19.9
SMA6J13A	SMA6J13CA	LG	BG	14.4	15.9	1	13	1	28	21.5
SMA6J14A	SMA6J14CA	LK	BK	15.6	17.2	1	14	1	25.9	23.2
SMA6J15A	SMA6J15CA	LM	BM	16.7	18.5	1	15	1	24.6	24.4
SMA6J16A	SMA6J16CA	LP	BP	17.8	19.7	1	16	1	23.1	26
SMA6J17A	SMA6J17CA	LR	BR	18.9	20.9	1	17	1	21.8	27.6
SMA6J18A	SMA6J18CA	LT	BT	20	22.1	1	18	1	20.6	29.2
SMA6J20A	SMA6J20CA	LV	BV	22.2	24.5	1	20	1	18.6	32.4
SMA6J22A	SMA6J22CA	LX	BX	24.4	26.9	1	22	1	16.9	35.5
SMA6J24A	SMA6J24CA	LZ	BZ	26.7	29.5	1	24	1	15.5	38.9
SMA6J26A	SMA6J26CA	ME	CE	28.9	31.9	1	26	1	14.3	42.1
SMA6J28A	SMA6J28CA	MG	CG	31.1	34.4	1	28	1	13.3	45.4
SMA6J30A	SMA6J30CA	MK	CK	33.3	36.8	1	30	1	12.4	48.4
SMA6J33A	SMA6J33CA	MM	CM	36.7	40.6	1	33	1	11.3	53.3
SMA6J36A	SMA6J36CA	MP	CP	40	44.2	1	36	1	10.4	58.1
SMA6J40A	SMA6J40CA	MR	CR	44.4	49.1	1	40	1	9.3	64.5
SMA6J43A	SMA6J43CA	MT	CT	47.8	52.8	1	43	1	8.7	69.4
SMA6J45A	SMA6J45CA	MV	CV	50	55.3	1	45	1	8.3	72.7
SMA6J48A	SMA6J48CA	MX	CX	53.3	58.9	1	48	1	7.8	77.4
SMA6J51A	SMA6J51CA	MZ	CZ	56.7	62.7	1	51	1	7.3	82.4
SMA6J54A	SMA6J54CA	NE	DE	60	66.3	1	54	1	6.9	87.1

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Part Number		Device Marking Code		Breakdown Voltage $V_{BR}@I_T$		Test Current I_T	Reverse Stand-off Voltage V_R	Max. Reverse Leakage $I_R@V_R$	Max. Peak Pulse Current I_{PPM}	Max. Clamping Voltage $V_C@I_{PPM}$
				Min	Max					
Uni	Bi	Uni	Bi	(V)		(mA)	(V)	(μA)	(A)	(V)
SMA6J58A	SMA6J58CA	NG	DG	64.4	71.2	1	58	1	6.5	93.6
SMA6J60A	SMA6J60CA	NK	DK	66.7	73.7	1	60	1	6.2	96.8
SMA6J64A	SMA6J64CA	NM	DM	71.1	78.6	1	64	1	5.9	103
SMA6J70A	SMA6J70CA	NP	DP	77.8	86	1	70	1	5.3	113
SMA6J75A	SMA6J75CA	NR	DR	83.3	92.1	1	75	1	5	121
SMA6J78A	SMA6J78CA	NT	DT	86.7	95.8	1	78	1	4.8	126
SMA6J85A	SMA6J85CA	NV	DV	94.4	104	1	85	1	4.4	137
SMA6J90A	SMA6J90CA	NX	DX	100	111	1	90	1	4.1	146
SMA6J100A	SMA6J100CA	NZ	DZ	111	123	1	100	1	3.7	162
SMA6J110A	SMA6J110CA	PE	EE	122	135	1	110	1	3.4	177
SMA6J120A	SMA6J120CA	PG	EG	133	147	1	120	1	3.1	193
SMA6J130A	SMA6J130CA	PK	EK	144	159	1	130	1	2.9	209
SMA6J150A	SMA6J150CA	PM	EM	167	185	1	150	1	2.5	243
SMA6J160A	SMA6J160CA	PP	EP	178	197	1	160	1	2.3	259
SMA6J170A	SMA6J170CA	PR	ER	189	209	1	170	1	2.2	275
SMA6J180A	SMA6J180CA	PT	ET	201	222	1	180	1	2.1	292
SMA6J188A	SMA6J188CA	PB	EB	209	231	1	188	1	2	304
SMA6J200A	SMA6J200CA	PV	EV	224	247	1	200	1	1.9	324
SMA6J220A	SMA6J220CA	PX	EX	246	272	1	220	1	1.7	356
SMA6J250A	SMA6J250CA	PZ	EZ	279	309	1	250	1	1.5	405

Notes:

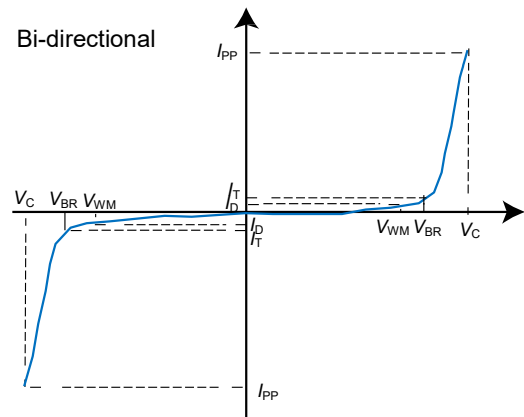
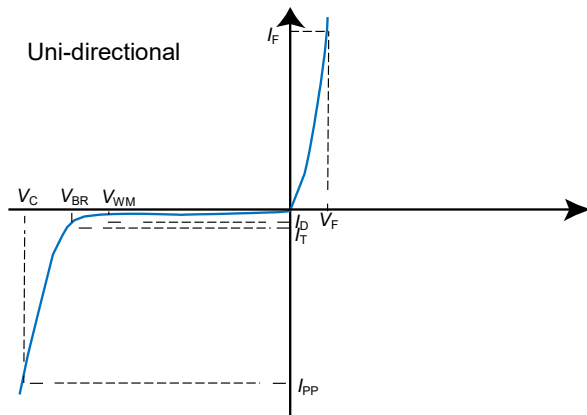
- For bidirectional type having V_R of 10 volts and less, the I_R should be doubled.
- For parts without A in the PN, the V_{BR} tolerance is $\pm 10\%$ and V_C is 5% higher than parts with A. The parts without A are currently available, but not recommended for new designs. The parts with A are preferred.
- $V_F < 3.5$ V for single die parts.

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I-V Curve Characteristics



Performance Curve for Reference ($T_A = 25^\circ\text{C}$ unless otherwise noted)

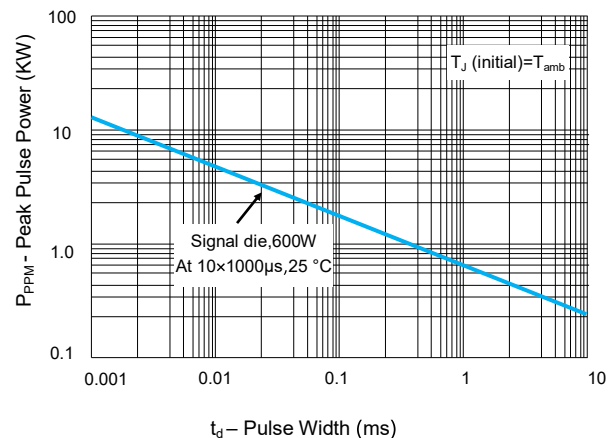
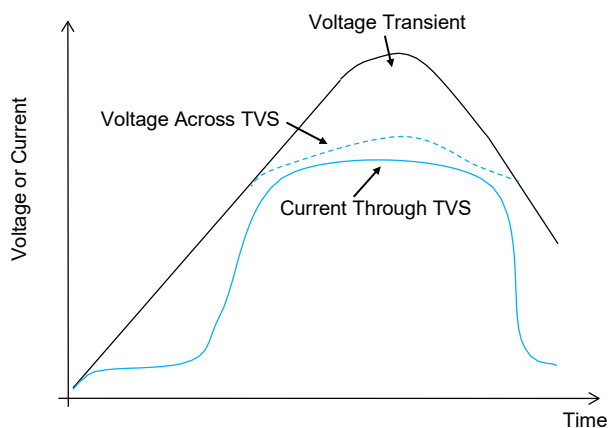


FIGURE 1 TVS Transients Clamping Waveform

FIGURE 2 Peak Pulse Power Rating Curve

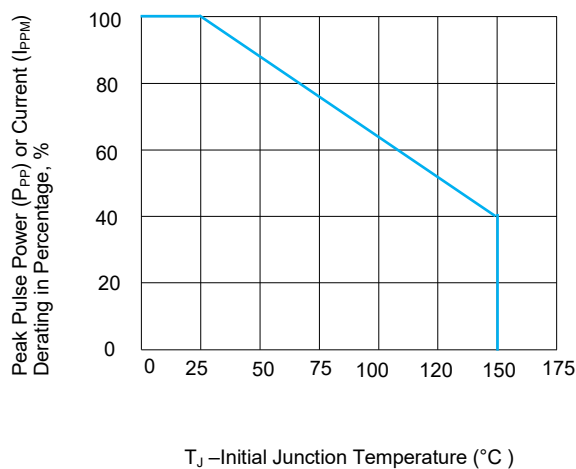


FIGURE 3 Peak Pulse Power Derating Curve

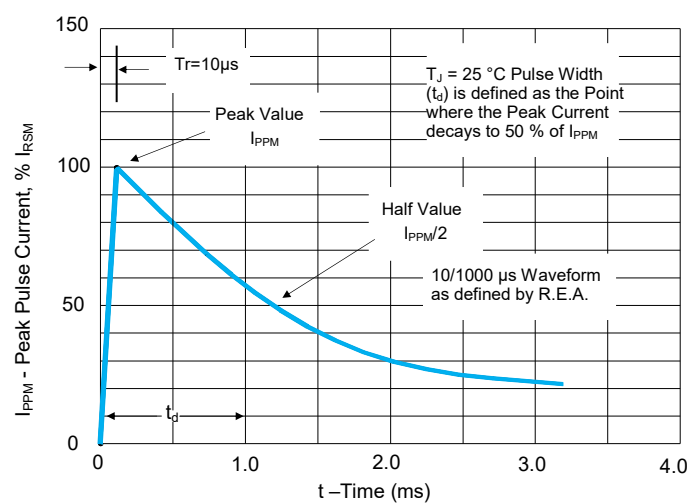


FIGURE 4 Pulse Waveform

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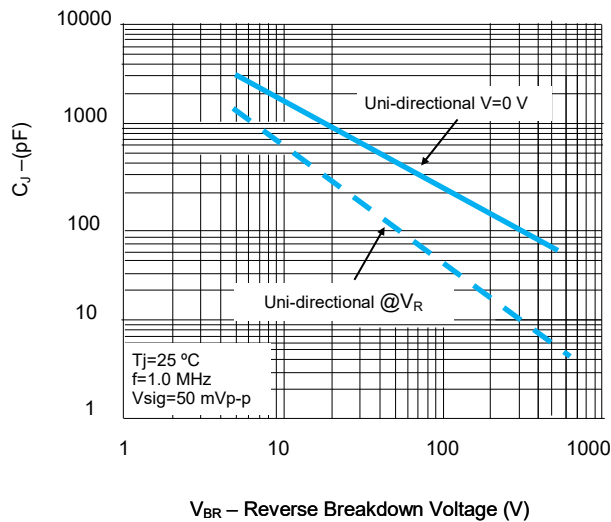


FIGURE 5 Typical Junction Capacitance

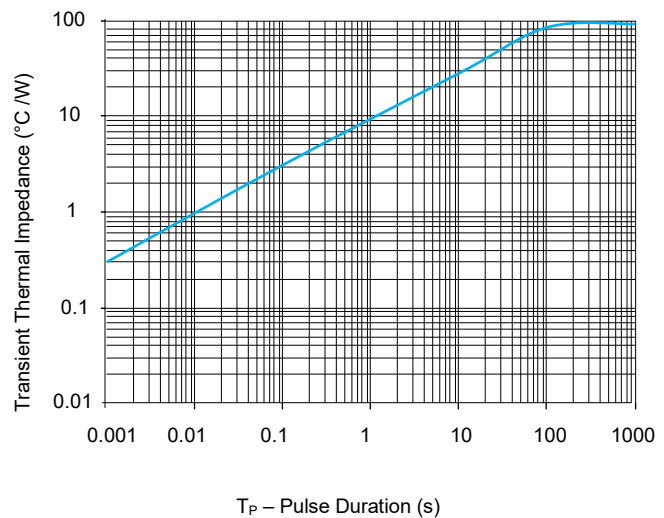


FIGURE 6 Typical Transient Thermal Impedance

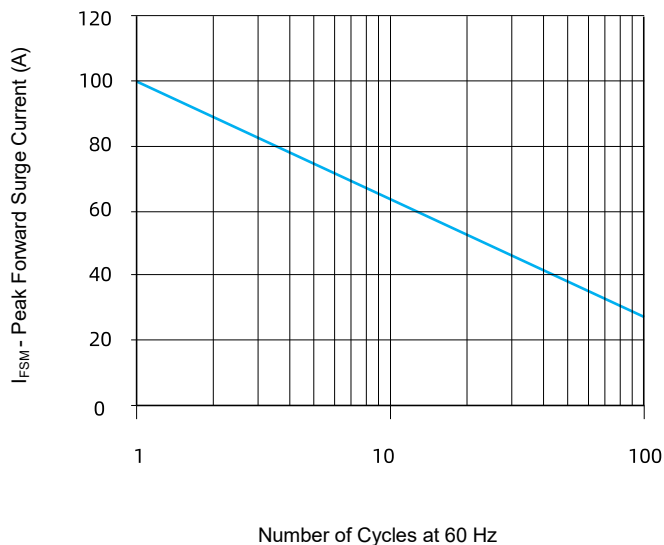


FIGURE 7 Maximum Non-Repetitive Forward Surge Current
Uni-Directional only

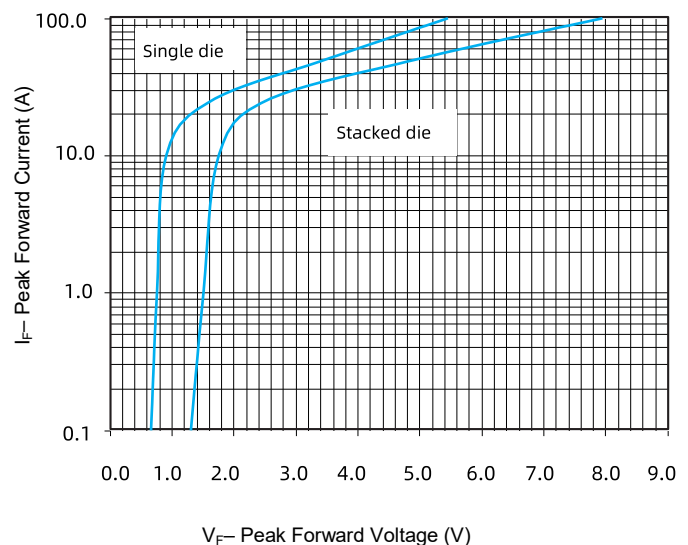


FIGURE 8 Peak Forward Drop vs Peak Forward Current
(Typical Values)

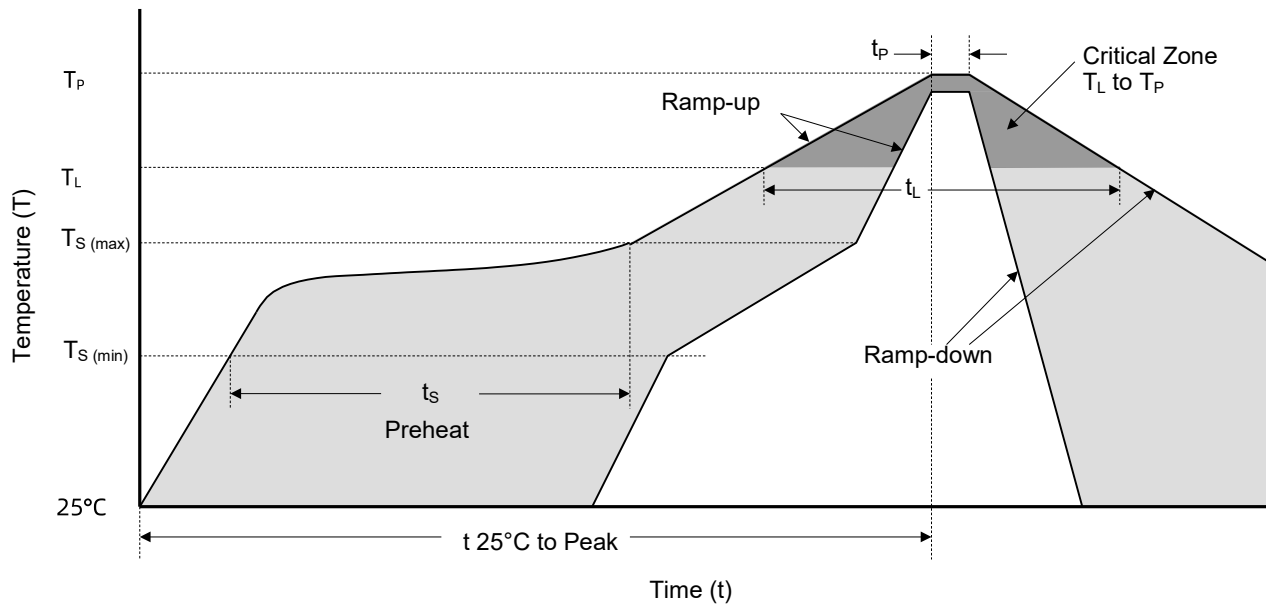
Environmental Specifications

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JESDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111

Physical Specifications

Weight	0.003 ounce, 0.093 grams
Case	JESD22DO214AA. Molded plastic body over glass passivated junction
Polarity	Color band denotes positive end (cathode) except Bidirectional
Terminal	Matte Tin-plated leads, Solderability per JESD22-B102

Soldering Parameters



Reflowing Condition

Reflow Soldering Parameters		Lead-Free Assembly
Pre-heat	Temperature Min ($T_{S(min)}$)	150 °C
	Temperature Max ($T_{S(max)}$)	200 °C
	Time (min to max) (t_s)	60 ~ 120 seconds
Average Ramp Up Rate (Liquidus Temp (T_L) to Peak		3 °C / second max.
$T_{S(max)}$ to T_L Ramp-up Rate		3 °C / second max.
Reflow	Temperature (T_L) (Liquidus)	217 °C
	Time (min to max) (t_L)	60 ~ 150 seconds
Peak Temperature (T_P)		260 ^{+0/-5} °C
Time of within 5 °C of Actual Peak Temperature (t_p)		20 ~ 40 seconds
Ramp-down Rate		6 °C / second max.
Time from 25 °C to Peak Temperature		8 Minutes max.
Do Not Exceed		260 °C

Packaging Information

Tape	Symbol	Dimension (mm)
	W	12.00±0.30/-0.10
	P ₀	4.00±0.10
	P ₁	8.00±0.10
	P ₂	2.00±0.05
	D ₀	1.55±0.05
	D ₁	1.55±0.05
	E	1.75±0.1
	F	5.50±0.05
	A ₀	2.79 ± 0.10
	B ₀	5.33 ± 0.10
	K ₀	2.36 ± 0.10
	T	0.30 ± 0.05

Reel Size	13" Reel	
	A	330 mm
	C	13.2 mm
	W ₁	12.5 mm

Part Number	Package	QTY (Reel)	Packaging Option	Packaging Specification
SMA6Jxxx	DO-214AC	5000 PCS	Tape & Reel – 12 mm tape/13" reel	EIA STD RS-481



ATTENTION

Usage

1. TVS must be operated in the specified ambient temp.
2. Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

1. If TVS is visually damaged, please replace it.
2. TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

1. Storage Temp. Range: (-55 to 150) °C.
2. Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder-ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

1. TVS should not be exposed to the open air, nor direct sunshine.
2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
3. TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

1. Do not knock TVS when installing, to avoid mechanical damage.
2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.